NSN 5961-01-159-3166

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Inclosure Material:

Metal

Overall Length:

0.070 inches

Overall Diameter:

0.110 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 collector to base voltage/static/emitter open and 16.0 collector to emitter voltage/static/base open and 1.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

35.00 milliamperes source cutoff current

Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 ribbon and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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